



# LED Display Product Data Sheet LTD-6410G-03

Spec No.: DS30-2000-341

Effective Date: 11/10/2000

Revision: -

**LITE-ON DCC**

**RELEASE**

BNS-OD-FC001/A4

**FEATURES**

- \* 0.56INCH (14.22mm) DIGIT HEIGHT
- \* CONTINUOUS UNIFORM SEGMENTS
- \* LOW POWER REQUIREMENT
- \* EXCELLENT CHARACTERS APPEARANCE
- \* HIGH BRIGHTNESS & HIGH CONTRAST
- \* WIDE VIEWING ANGLE
- \* SOLID STATE RELIABILITY
- \* CATEGORIZED FOR LUMINOUS INTENSITY

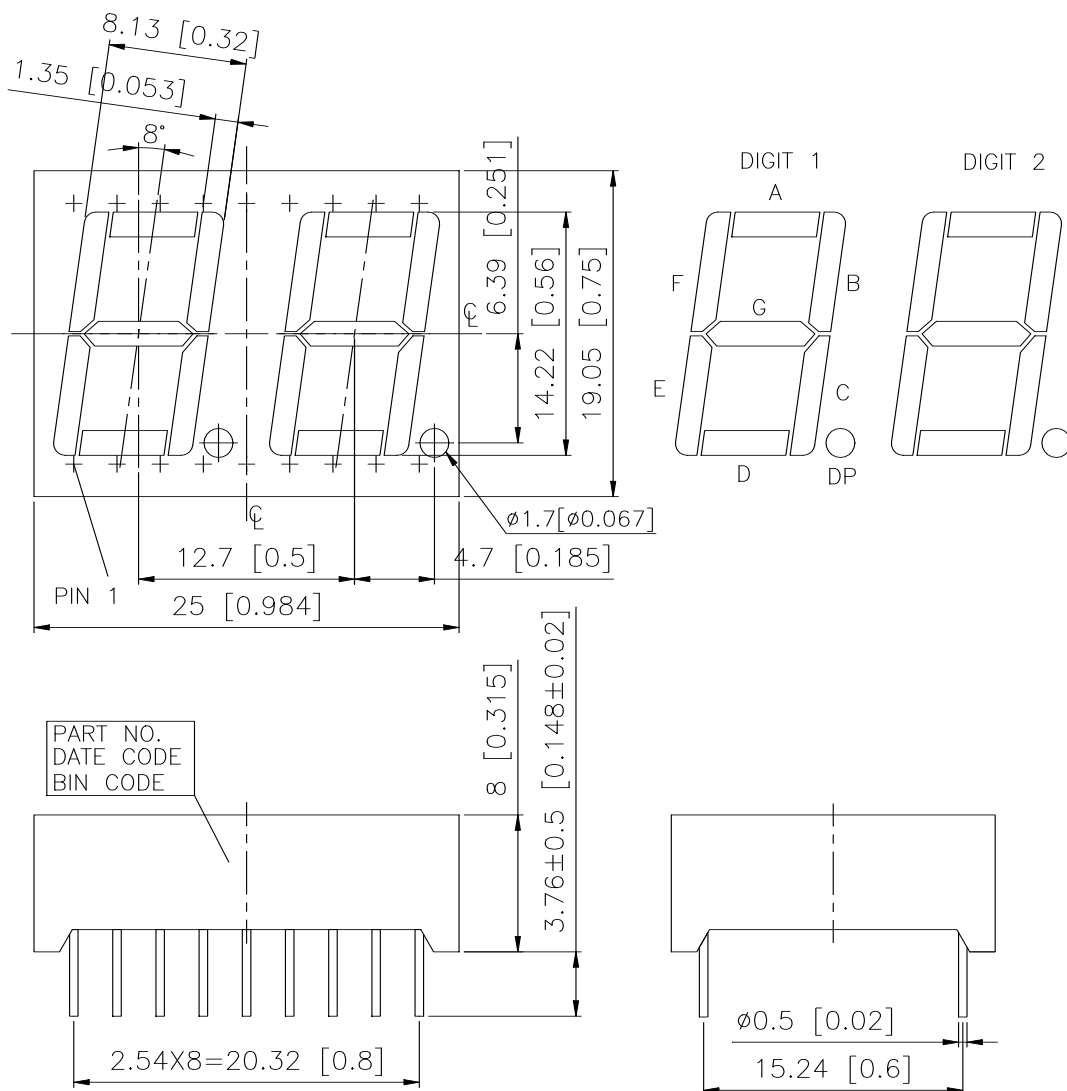
**DESCRIPTION**

The LTD-6410G-03 is a 0.56inch (14.22mm) digit height dual digit seven-segment display. The device utilizes green LED chips, which are made from GaP on GaP substrate, and has a black face and white segments.

**DEVICE**

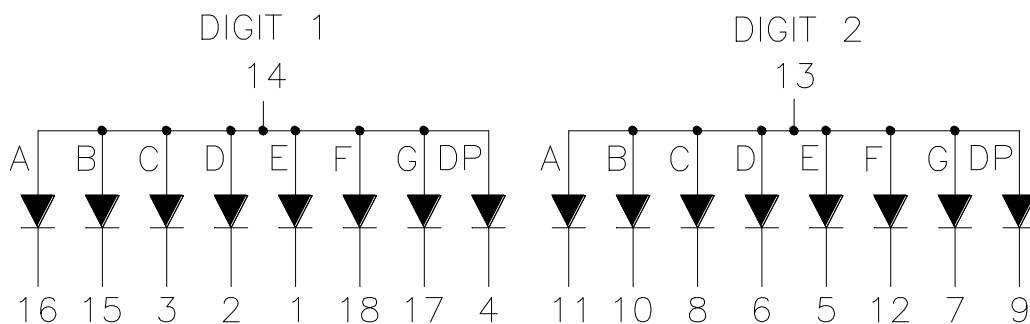
PART NO.	DESCRIPTION
GREEN	COMMON ANODE
LTD-6410G-03	RT. HAND DECIMAL

## PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm unless otherwise noted.

## INTERNAL CIRCUIT DIAGRAM



**PIN CONNECTION**

<b>No.</b>	<b>CONNECTION</b>
1	CATHODE E (DIGIT 1)
2	CATHODE D (DIGIT 1)
3	CATHODE C (DIGIT 1)
4	CATHODE DP (DIGIT 1)
5	CATHODE E (DIGIT 2)
6	CATHODE D (DIGIT 2)
7	CATHODE G (DIGIT 2)
8	CATHODE C (DIGIT 2)
9	CATHODE DP (DIGIT 2)
10	CATHODE B (DIGIT 2)
11	CATHODE A (DIGIT 2)
12	CATHODE F (DIGIT 2)
13	COMMON ANODE (DIGIT 2)
14	COMMON ANODE (DIGIT 1)
15	CATHODE B (DIGIT 1)
16	CATHODE A (DIGIT 1)
17	CATHODE G (DIGIT 1)
18	CATHODE F (DIGIT 1)

**ABSOLUTE MAXIMUM RATING AT Ta=25°C**

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Chip	75	mW
Peak Forward Current Per Chip ( 1/10 Duty Cycle, 0.1ms Pulse Width )	100	mA
Continuous Forward Current Per Chip	25	mA
Derating Linear From 25°C Per Chip	0.33	mA/°C
Reverse Voltage Per Chip	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm below seating plane		

**TRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	870	2400		μcd	I <sub>F</sub> =10mA
Peak Emission Wavelength	λ <sub>p</sub>		565		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		30		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		569		nm	I <sub>F</sub> =20mA
Forward Voltage Per Chip	V <sub>F</sub>		2.1	2.6	V	I <sub>F</sub> =20mA
Reverse Current Per Chip	I <sub>R</sub>			100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>F</sub> =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

## TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

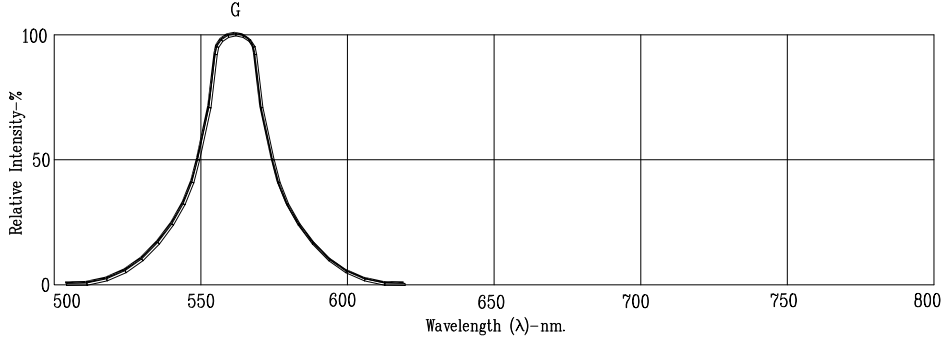


Fig.1. RELATIVE INTENSITY VS. WAVELENGTH

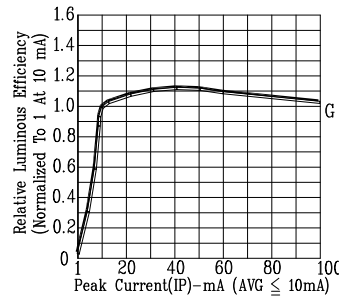


Fig.2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHz)

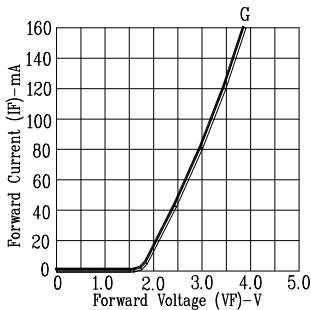


Fig.3. FORWARD CURRENT VS. FORWARD VOLTAGE

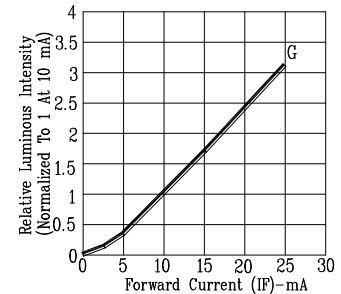


Fig.4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

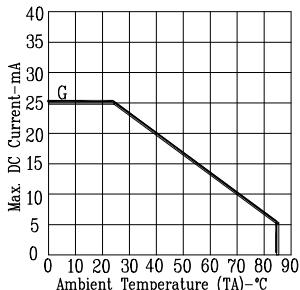


Fig.5. MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE.

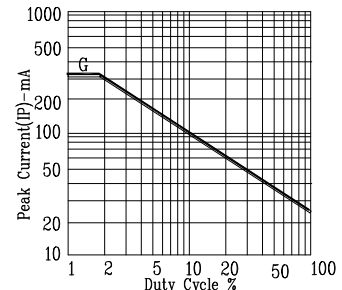


Fig.6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE: G=GREEN